

**ANALOG DIAGNOSIS
AND OPTIMIZATION TECHNOLOGY
FOR EXPERIMENTAL VALIDATION**

John W. Bandler

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Atlanta, GA, June 14, 1993



Introduction

questions (*Rautio, 1992*)

- design of experiments
- error analysis
- sensitivity analysis
- experimental significance
- experimental objective

our aim

- to find answers in microwave CAD technology
- to find answers in analog fault diagnosis
- to suggest software solutions now available
- to suggest some open areas for investigation



Background (*Rautio, 1991*)

no sensitivity evaluation

no error analysis

measurements made at a difficult frequency
(data with large scatter)

too many "confounding" variables

the experimenter has a desired outcome in mind

incorrect objective



Our Points of View

we could take the view that the feature being measured is a "fault" to be diagnosed

or we could take the view that the feature being measured is obscured by elements which may be uncertain or "faulty"

in validation a fluctuation or uncertainty is often under investigation; the experiment must be designed so that the effect is not obscured

examine common denominators of experimental validation, device characterization, parameter extraction and network testing such as approach, objectives, accuracy, uniqueness

soft (faults) deviations

the (faulty) element deviates from its nominal value without reaching its extreme bounds

result from manufacturing tolerances, aging, parasitic effects



Relevant Approaches from Fault Analysis

fault dictionary approach

dictionary construction

selecting an optimal set of measurements

dealing with ambiguity sets

fault isolation techniques

efficient methods of fault simulation

parameter identification techniques

DC or time-domain testing of nonlinear networks

multifrequency testing of linear networks

select test frequencies to optimize a measure of the solvability of the diagnosis equations?

how solvable are the equations given an optimal choice of test frequencies?

linear techniques for element value determination

fault verification techniques (consistency checking)

techniques to determine the most likely faults



CAT Techniques

computer-aided analog testing

fault detection

fault location

parameter identification

postproduction tuning

uniqueness often essential

sensitivity to changes, fluctuations and uncertainties
should be exposed

some challenges

robustness against deviations of other elements

robustness against measurement uncertainties

establish a measure of testability

how to use the minimum number of tests

insufficient data (degree of diagnosability)



Analog Circuit Theory

1. Circuit Analysis and Simulation

component values assumed

all possible solutions of interest

relevant to experimental validation

2. Circuit Design and Optimization

component values optimizable

good solutions of interest

more relevant to experimental validation

3. Circuit Diagnosis and Testing

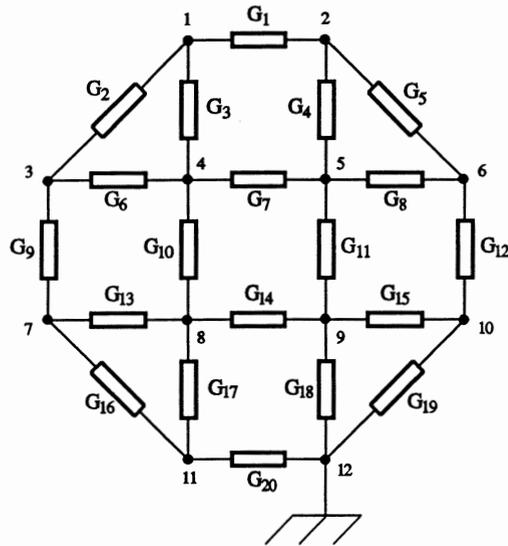
components under investigation

unique solutions of interest

most relevant to experimental validation

(Bandler and Salama, "Fault diagnosis of analog circuits", Proc. IEEE, 1985, pp. 1279-1325)

Analog Diagnosis Problem



resistive mesh circuit

only external nodes are available for excitation and measurements

Analog Diagnosis Using ℓ_1 Optimization

$$\underset{\mathbf{x}}{\text{minimize}} \quad \sum_{i=1}^n |\Delta x_i / x_i^0|$$

subject to

$$V_1^c(\mathbf{x}) - V_1^m = 0$$

⋮

$$V_K^c(\mathbf{x}) - V_K^m = 0$$

where

$\mathbf{x} = [x_1 \ x_2 \ \dots \ x_n]^T$ circuit parameters

x^0 nominal or assumed parameter values

$\Delta x_i = x_i - x_i^0$ deviations from the nominal or assumed values

V_1^m, \dots, V_K^m measurements on the circuit under test

$V_1^c(\mathbf{x}), \dots, V_K^c(\mathbf{x})$ calculated circuit responses

Analog Diagnosis Using Huber Optimization

penalty function approach

$$\underset{\mathbf{x}}{\text{minimize}} \sum_{j=1}^{n+K} \rho_k(f_j(\mathbf{x}))$$

where

$$f_i(\mathbf{x}) = \Delta x_i / x_i^0, \quad i = 1, 2, \dots, n$$

$$f_{n+i}(\mathbf{x}) = \beta_i (V_i^c(\mathbf{x}) - V_i^m), \quad i = 1, 2, \dots, K$$

β_i are appropriate multipliers for the penalty terms

Huber Functions

$$\rho_k(f) = \begin{cases} f^2/2 & \text{if } |f| \leq k \\ k|f| - k^2/2 & \text{if } |f| > k \end{cases}$$

where k is a positive constant

the Huber function ρ_k is a hybrid of the least-squares (ℓ_2) (when $|f| \leq k$) and the ℓ_1 (when $|f| > k$)

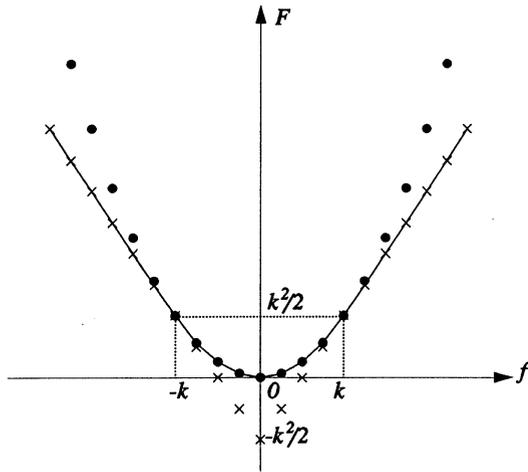
Huber Optimization

$$\underset{\mathbf{x}}{\text{minimize}} F(\mathbf{x}) \triangleq \sum_{j=1}^m \rho_k(f_j(\mathbf{x}))$$

where $\mathbf{x} = [x_1 \ x_2 \ \dots \ x_n]^T$ is the set of variables

$f_j, j = 1, 2, \dots, m,$ are error functions

Huber Function as a Hybrid ℓ_1 / ℓ_2



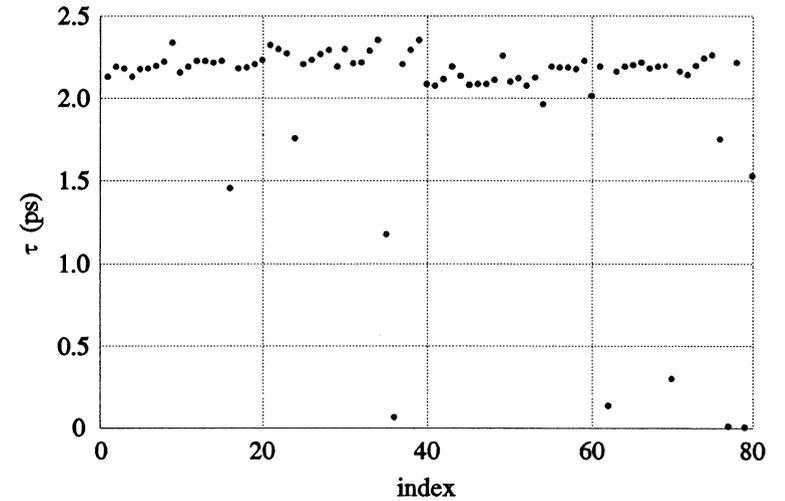
the Huber, ℓ_1 and ℓ_2 objective functions in the one-dimensional case

the strikes represent the discrete points on the ℓ_1 curve

the dots represent the discrete points on the ℓ_2 curve

the continuous curve indicates the Huber objective function

Data Containing Wild Points



run chart of the FET time-delay τ

extracted from multi-device measurements

Huber Solution of Analog Diagnosis Problem

FAULT LOCATION OF THE RESISTIVE MESH CIRCUIT

Element	Nominal Value	Actual Value	Percentage Deviation		
			Actual	ℓ_1	Huber
G_1	1.0	0.98	-2.0	0.00	-0.11
G_2	1.0	0.50	-50.0*	-48.89	-47.28
G_3	1.0	1.04	4.0	0.00	-2.46
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G_8	1.0	1.05	5.0	0.00	-0.41
G_9	1.0	1.02	2.0	2.41	3.75
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G_{12}	1.0	1.01	1.0	2.73	1.32
G_{13}	1.0	0.99	-1.0	0.00	-0.26
G_{13}	1.0	0.98	-2.0	0.00	-0.50
G_{14}	1.0	1.02	2.0	0.00	-0.05
G_{15}	1.0	0.96	-4.0	-3.36	-2.67
G_{16}	1.0	1.02	2.0	0.00	-0.61
G_{17}	1.0	0.50	-50.0*	-50.09	-47.33
G_{18}	1.0	0.98	-2.0	-1.41	-3.81
G_{19}	1.0	0.96	-4.0	-4.40	-4.72

* Faults

Relevant Optimization and Analog Diagnosis Benchmarks

"A nonlinear programming approach to optimal design centering, tolerancing and tuning," (*IEEE Trans. CAS*, 1976)

"An interactive optimal post-production tuning technique utilizing simulated sensitivities and response measurements," (*MTT-S Symp.*, 1981)

"Fault isolation in linear analog circuits using the L1 norm," (*CAS Symp.*, 1982)

"Integrated approach to microwave post production tuning," (*MTT-S Symp.*, 1983)

"Microwave device modelling using efficient ℓ_1 optimization: a novel approach," (*MTT-S Symp.*, 1986)

"Robustizing circuit optimization using Huber functions," (*MTT-S Symp.*, 1993)

Experimental Validation of Microstrip Filter Designs

conventional use of EM simulation to validate designs

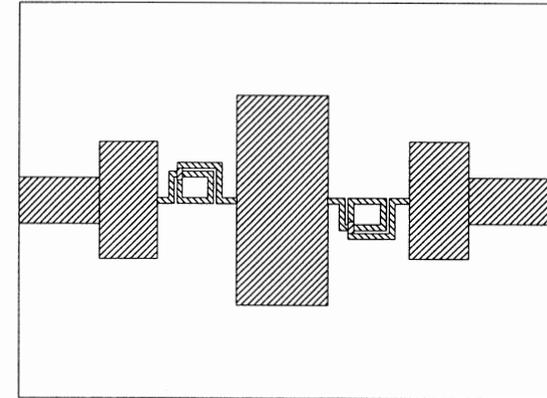
low-pass microstrip filter: microstrip components derived from a synthesized LC prototype (*Swanson, 1991*)

common sense judgement used to "validate" the design

sophisticated validation algorithms could enhance the common sense judgement approach

A Low-Pass Microstrip Filter

(*Swanson, 1991*)



built on a 25 mil thick alumina substrate with a relative dielectric constant of 9.8

the rectangular inductors utilize air bridges with vias

EM Simulation of the Low-Pass Microstrip Filter
(Swanson, 1991)

for simulation the whole structure is partitioned into individual components

approximate simulation times per one frequency point:

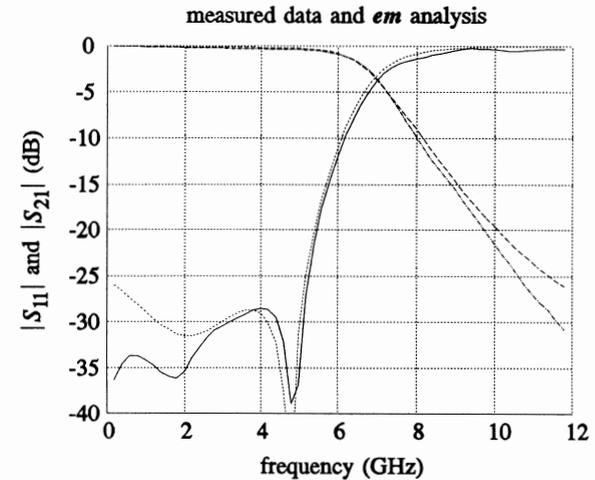
- 100 seconds for the inductor
- 10 seconds for the center capacitor
- 8 seconds for the end capacitor

the resulting S parameters of individual components are combined to determine the S parameters of the overall filter

symmetry of the filter is utilized by simulating only one inductor and one end capacitor

additional pieces of transmission lines are added for each component and de-embedded for better accuracy and to account for discontinuities at both sides of each capacitor

EM Simulation and Measurements of the Low-Pass Filter
(Swanson, 1991)



(---) simulated $|S_{11}|$ (-----) measured $|S_{11}|$
(.....) simulated $|S_{21}|$ (—) measured $|S_{21}|$

electromagnetic simulation using em^{TM}

very good approximation of filter behaviour, in particular around the cut-off frequency



Optimization Technology for Automated CAD

parameterized models

based on physics, fields, circuits, experiments

circuit theory for interconnection

numerical algorithms for simulation and optimization

objectives

meet parameter constraints

exceed performance specifications

tolerance optimization

yield maximization

cost minimization

uniqueness not essential

sensitivity to changes, fluctuations and uncertainties

should be considered but their effects minimized



Integrated Approach to Microwave Design

(Bandler Liu and Tromp, 1975)

benchmark considerations of the integrated approach

optimal design centering

optimal design tolerancing

optimal design tuning

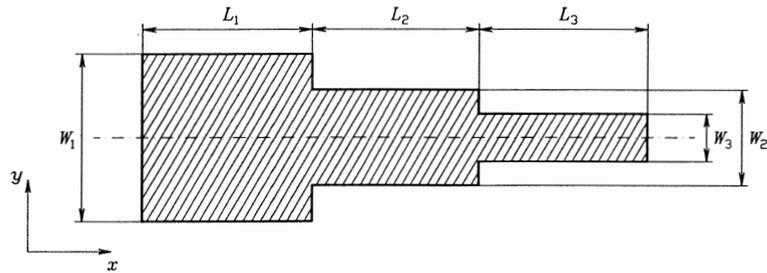
parasitic effects

uncertainties in models and reference plane

mismatched terminations

we now need an integrated approach to experimental validation to address some of Rautio's questions

Three-Section 3:1 Microstrip Impedance Transformer



designed on a 0.635 mm thick substrate with relative dielectric constant of 9.7

the source and load impedances are 50 and 150 ohms

design specification set for the input reflection coefficient

$$|S_{11}| \leq 0.12, \text{ from 5 GHz to 15 GHz}$$

normal distributions with 2% standard deviations assumed for W_1 , W_2 and W_3 and 1% standard deviations assumed for L_1 , L_2 and L_3

EM Simulation of the Microstrip Transformer

decomposed into three components simulated as two-ports

the first two sections simulated as step discontinuities

the last section simulated as a microstrip line

data base of simulated results

three component level Q-models established for each section of the transformer at the nominal point using *em*TM

the entire transformer structure also simulated as one piece

simulation results by the two approaches were practically identical

Yield-Driven Electromagnetic Optimization of the Microstrip Transformer

yield optimization started from the solution of a nominal minimax design

single vs. multilevel modeling - two experiments:

yield optimization using single-level (component) modeling

yield optimization using two-level (component and circuit response) modeling

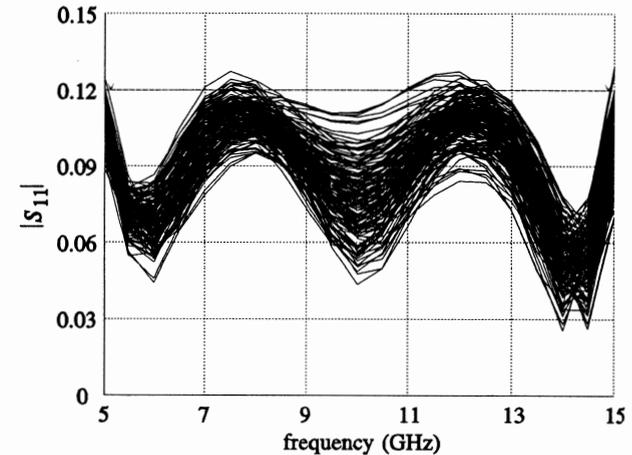
the Q-models were updated during optimization whenever necessary

selection of optimization variables - two experiments:

all six variables W_1 , W_2 , W_3 , L_1 , L_2 and L_3 selected

only three variables W_1 , W_2 and W_3 selected

Three-Section Microstrip Transformer After Yield Optimization



modulus of the reflection coefficient vs. frequency

optimization using single-level (component) Q-models

100 statistical outcomes used for yield optimization

yield is increased to 86%

Yield Sensitivity Analysis of the Microstrip Transformer

three-section 3:1 microstrip transformer

sensitivity analysis performed at the solution of yield optimization with all six optimization variables

seven experiments:

the specification is swept from 0.10 to 0.13

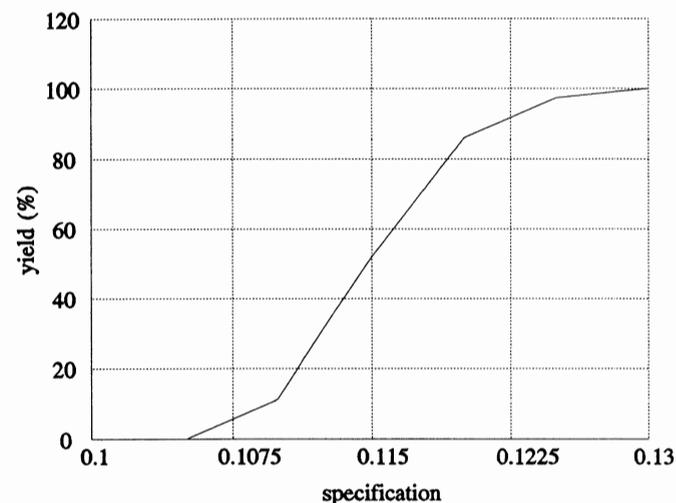
each of the six optimization variables is individually swept

yield is very sensitive to the widths of all the sections and is quite insensitive to the lengths

250 Monte Carlo outcomes used for yield estimation

the results were obtained with little additional computational effort

Yield Sensitivity of the Microstrip Transformer



yield vs. specification on $|S_{11}|$

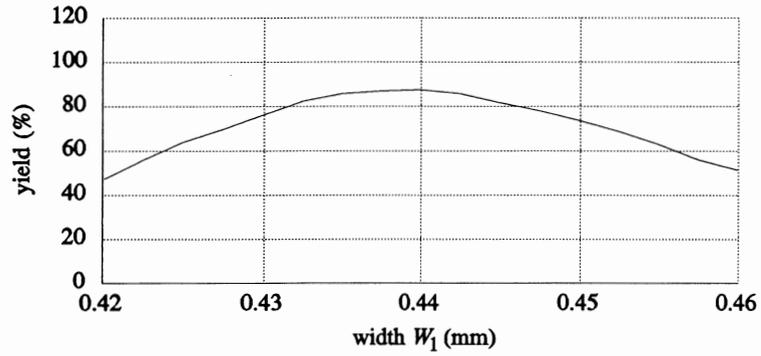
high sensitivity of yield w.r.t. the specification

yield varies from 0% to 100% over a very small range of the specification

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer



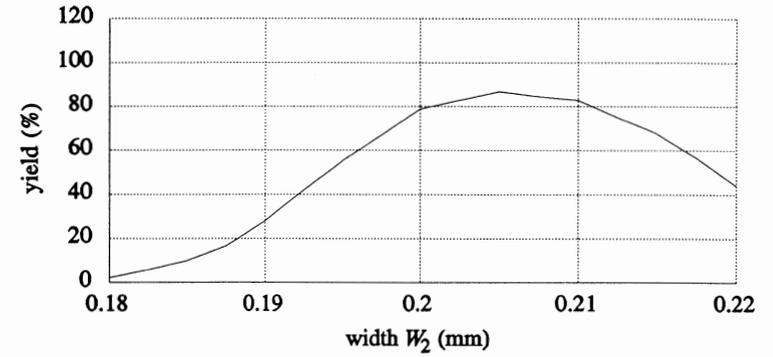
yield vs. W_1

relatively high sensitivity of yield w.r.t. W_1

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer

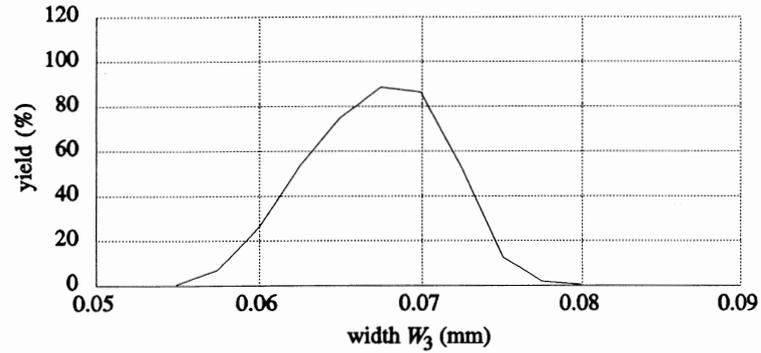


yield vs. W_2

high sensitivity of yield w.r.t. W_2

yield estimated with 250 Monte Carlo outcomes

Yield Sensitivity of the Microstrip Transformer

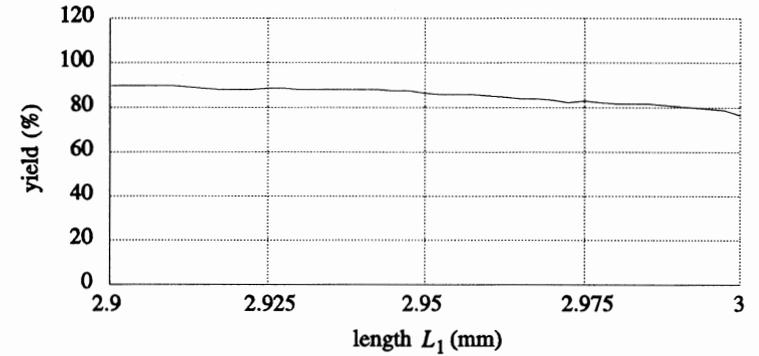


yield vs. W_3

high sensitivity of yield w.r.t. W_3

yield estimated with 250 Monte Carlo outcomes

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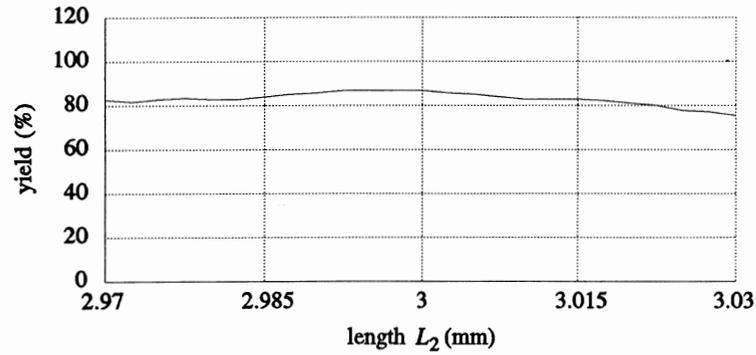


yield vs. L_1

low sensitivity of yield w.r.t. L_1

yield estimated with 250 Monte Carlo outcomes

Yield Sensitivity of the Microstrip Transformer

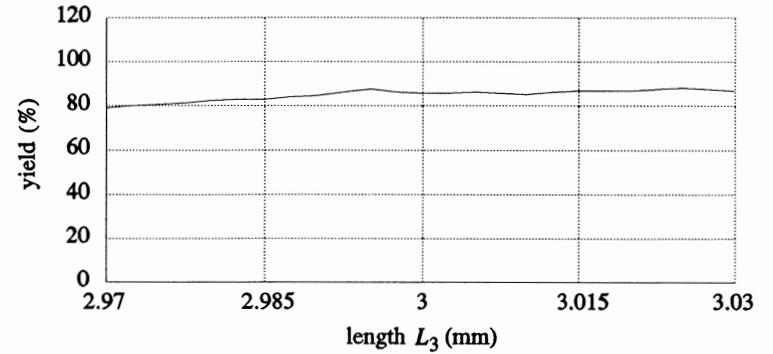


yield vs. L_2

low sensitivity of yield w.r.t. L_2

yield estimated with 250 Monte Carlo outcomes

Yield Sensitivity of the Microstrip Transformer



yield vs. L_3

low sensitivity of yield w.r.t. L_3

yield estimated with 250 Monte Carlo outcomes



Software Implementing Statistical/Diagnosis Concepts

RoMPE™ (1988)

FET parameter extraction (DC data, S parameters)

HarPE™ (1989)

statistical FET parameter extraction (DC, SS, HB)

OSA90™ (1990)

friendly optimization engine for performance- and yield-driven design

OSA90/hope™ (1991)

OSA90 integrated with unified DC/SS/HB

these CAD tools merge multi-circuit/device/domain/bias modeling principles with novel ℓ_1 objectives to enhance precision and uniqueness

robustized modeling and design using Huber functions are coming



Empipe™ (1992)

smart connection of OSA90/hope™ with Sonnet's *em*™ field simulator for interprocessing circuit/field/measurement data

a significant step towards the required integrated approach offering

simulation, modeling, parameter extraction
optimization, sensitivity analysis, statistical analysis
error analysis (probability of satisfying error specs)
automated processing of circuit/field/measurement data
fixed or optimizable geometries simulated by *em*™

recent applications include

EM microstrip filter design
yield-driven direct EM optimization
EM statistical sensitivity analyses

more relevant experimental validation applications to come!



**Parameterized (Optimizable)
Microstrip Library of Empipe™**

bend
cross junction
double patch capacitors
interdigital capacitors
line
mitered bend
open stub
overlay double patch capacitors
rectangular structure
spiral inductors
step junction
symmetrical and asymmetrical folded double stubs
symmetrical and asymmetrical gaps
symmetrical and asymmetrical double stubs
T junction



Conclusions

sensitivity evaluation
 well-understood in analysis, design and testing

error analysis
 already part of statistical modeling/design systems

measurements made at a difficult frequency
 see work on multifrequency testing

too many "confounding" variables
 similar treatment as for "soft faults"

the experimenter has a desired outcome in mind
 quite an opposite outcome in fault diagnosis!

incorrect objective
 answered by diagnosability and testability theory

CAD software
 frameworks available for immediate exploitation

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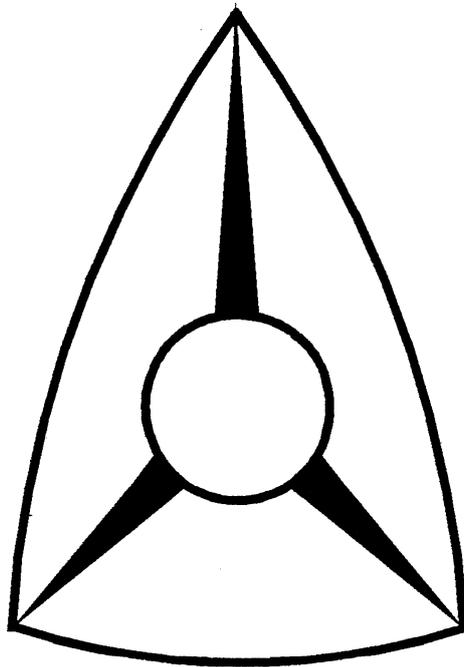
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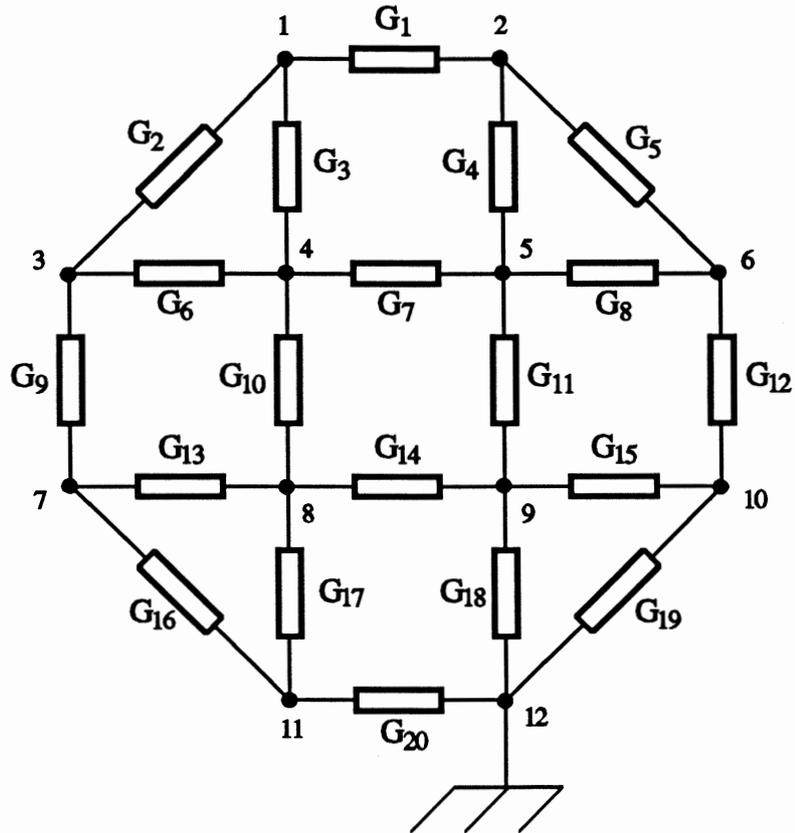
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where

- | | |
|---|---|
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| x^0 | nominal or assumed parameter values |
| $\Delta x_i = x_i - x_i^0$ | deviations from the nominal or assumed values |
| V_1^m, \dots, V_K^m | measurements on the circuit under test |
| $V_1^c(\mathbf{x}), \dots, V_K^c(\mathbf{x})$ | calculated circuit responses |



Analog Diagnosis Using Huber Optimization

penalty function approach

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Huber Optimization

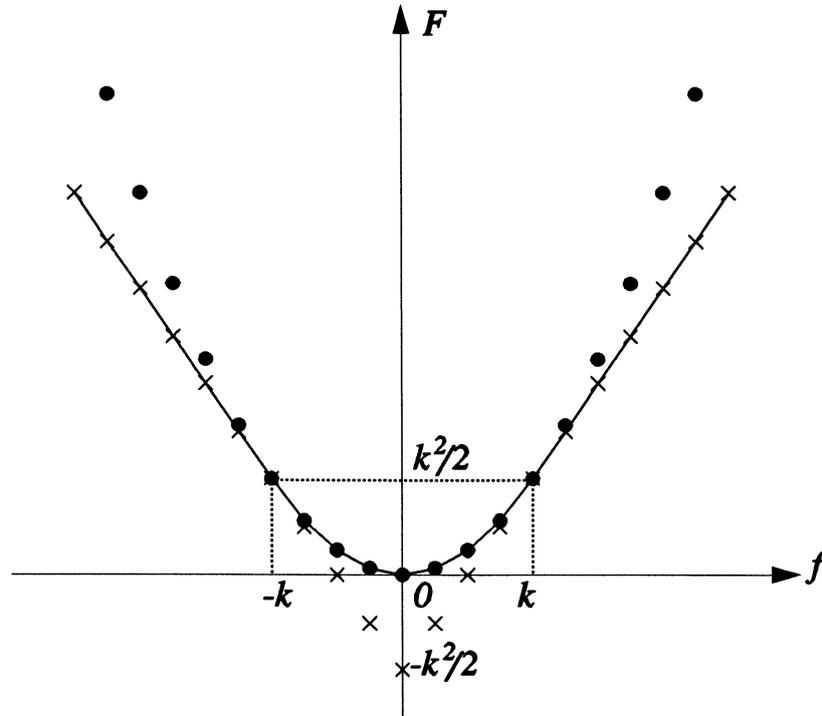
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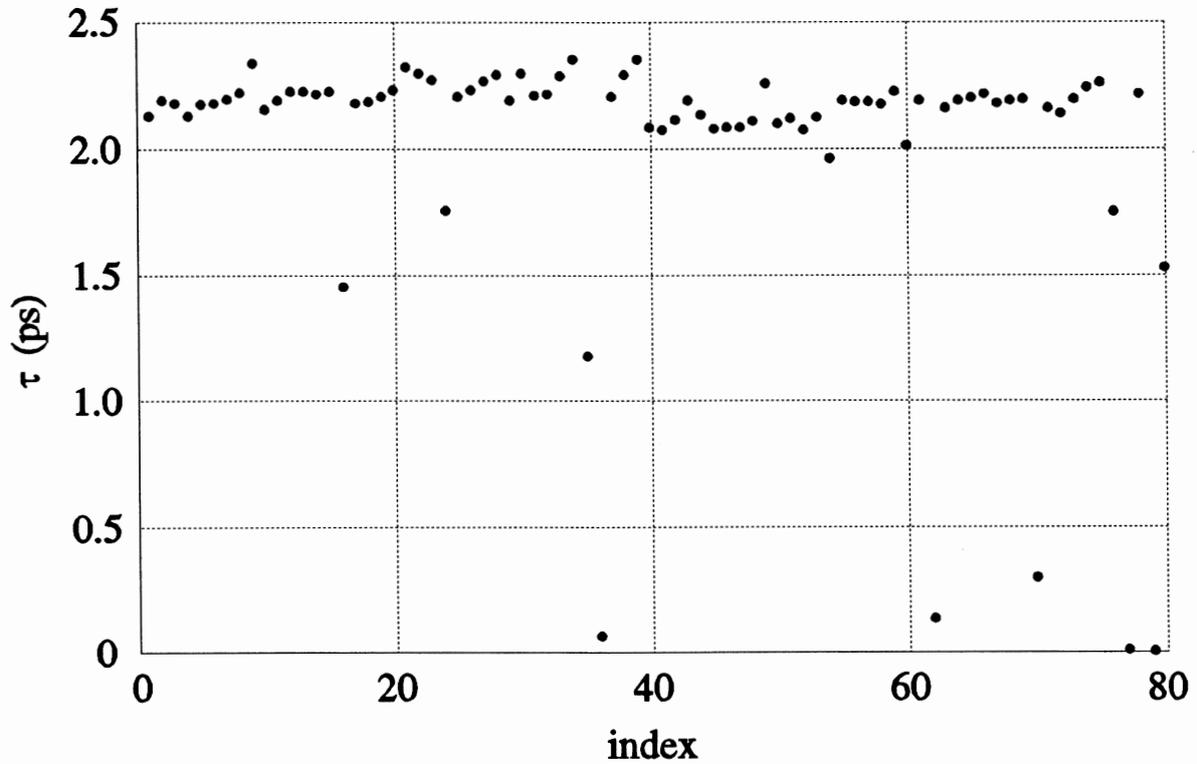
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low-pass microstrip filter: microstrip components derived from a synthesized LC prototype (*Swanson, 1991*)

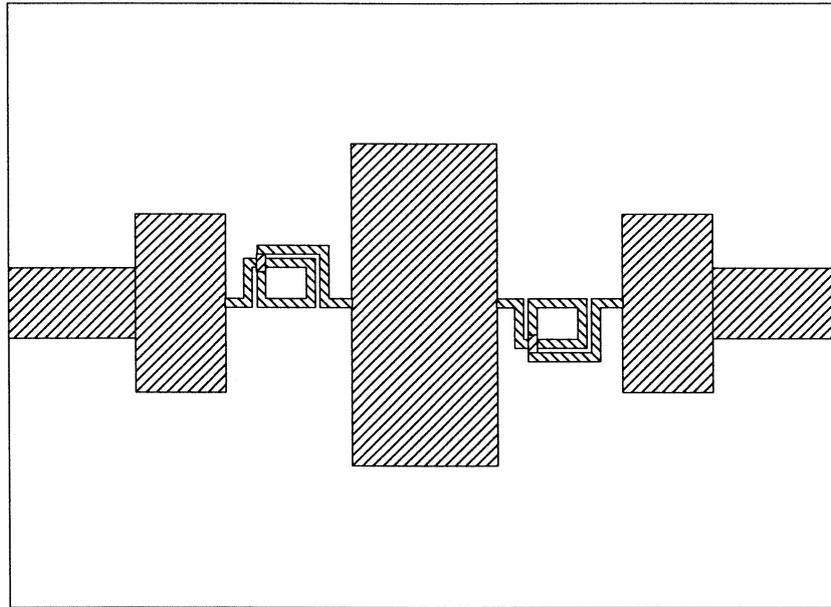
common sense judgement used to "validate" the design

sophisticated validation algorithms could enhance the common sense judgement approach



A Low-Pass Microstrip Filter

(Swanson, 1991)



built on a 25 mil thick alumina substrate with a relative dielectric constant of 9.8

the rectangular inductors utilize air bridges with vias



EM Simulation of the Low-Pass Microstrip Filter

(Swanson, 1991)

for simulation the whole structure is partitioned into individual components

approximate simulation times per one frequency point:

100 seconds for the inductor

10 seconds for the center capacitor

8 seconds for the end capacitor

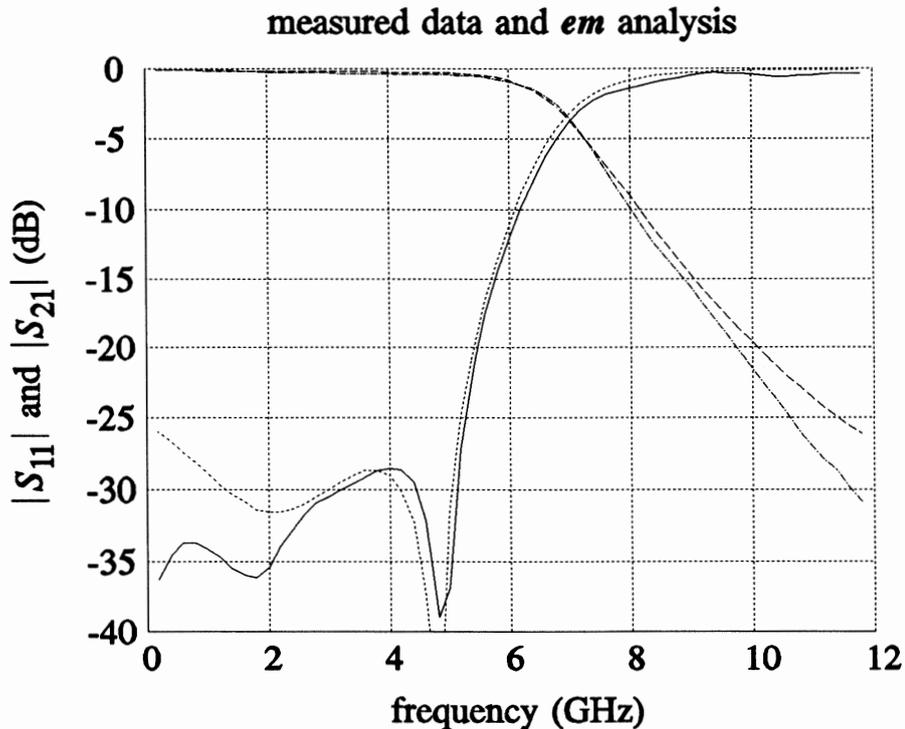
the resulting S parameters of individual components are combined to determine the S parameters of the overall filter

symmetry of the filter is utilized by simulating only one inductor and one end capacitor

additional pieces of transmission lines are added for each component and de-embedded for better accuracy and to account for discontinuities at both sides of each capacitor



EM Simulation and Measurements of the Low-Pass Filter (Swanson, 1991)



(---) simulated $|S_{11}|$ (-·-·-·) measured $|S_{11}|$
(·····) simulated $|S_{21}|$ (—) measured $|S_{21}|$

electromagnetic simulation using *em*TM

very good approximation of filter behaviour, in particular
around the cut-off frequency



Optimization Technology for Automated CAD

parameterized models

based on physics, fields, circuits, experiments

circuit theory for interconnection

numerical algorithms for simulation and optimization

objectives

meet parameter constraints

exceed performance specifications

tolerance optimization

yield maximization

cost minimization

uniqueness not essential

sensitivity to changes, fluctuations and uncertainties

should be considered but their effects minimized



Integrated Approach to Microwave Design

(Bandler Liu and Tromp, 1975)

benchmark considerations of the integrated approach

optimal design centering

optimal design tolerancing

optimal design tuning

parasitic effects

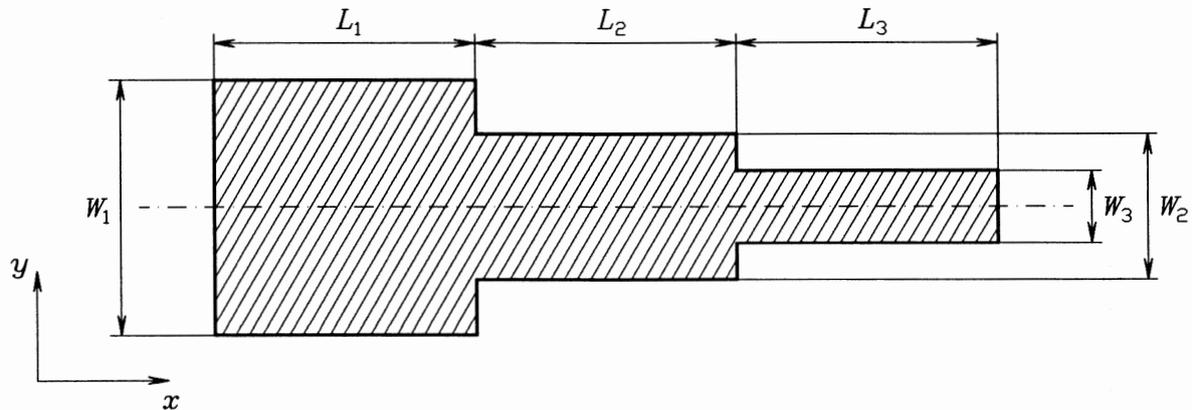
uncertainties in models and reference plane

mismatched terminations

we now need an integrated approach to experimental validation to address some of Rautio's questions



Three-Section 3:1 Microstrip Impedance Transformer



designed on a 0.635 mm thick substrate with relative dielectric constant of 9.7

the source and load impedances are 50 and 150 ohms

design specification set for the input reflection coefficient

$$|S_{11}| \leq 0.12, \text{ from 5 GHz to 15 GHz}$$

normal distributions with 2% standard deviations assumed for W_1 , W_2 and W_3 and 1% standard deviations assumed for L_1 , L_2 and L_3



EM Simulation of the Microstrip Transformer

decomposed into three components simulated as two-ports

the first two sections simulated as step discontinuities

the last section simulated as a microstrip line

data base of simulated results

three component level Q-models established for each section of the transformer at the nominal point using *em*TM

the entire transformer structure also simulated as one piece

simulation results by the two approaches were practically identical



Yield-Driven Electromagnetic Optimization of the Microstrip Transformer

yield optimization started from the solution of a nominal minimax design

single vs. multilevel modeling - two experiments:

yield optimization using single-level (component) modeling

yield optimization using two-level (component and circuit response) modeling

the Q-models were updated during optimization whenever necessary

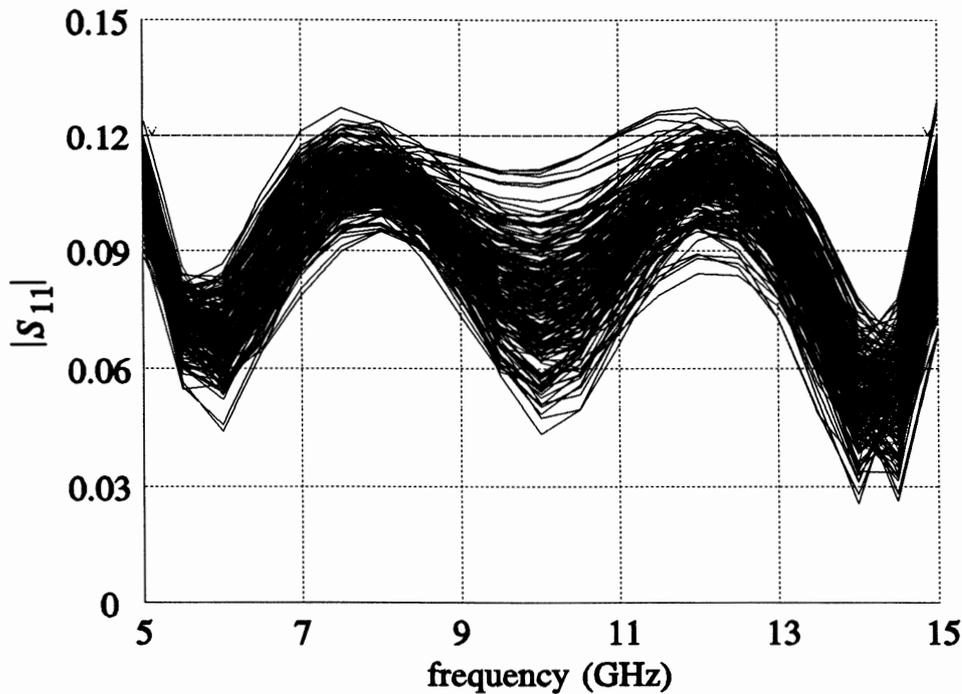
selection of optimization variables - two experiments:

all six variables W_1 , W_2 , W_3 , L_1 , L_2 and L_3 selected

only three variables W_1 , W_2 and W_3 selected



Three-Section Microstrip Transformer After Yield Optimization



modulus of the reflection coefficient vs. frequency

optimization using single-level (component) Q-models

100 statistical outcomes used for yield optimization

yield is increased to 86%



Yield Sensitivity Analysis of the Microstrip Transformer

three-section 3:1 microstrip transformer

sensitivity analysis performed at the solution of yield optimization with all six optimization variables

seven experiments:

the specification is swept from 0.10 to 0.13

each of the six optimization variables is individually swept

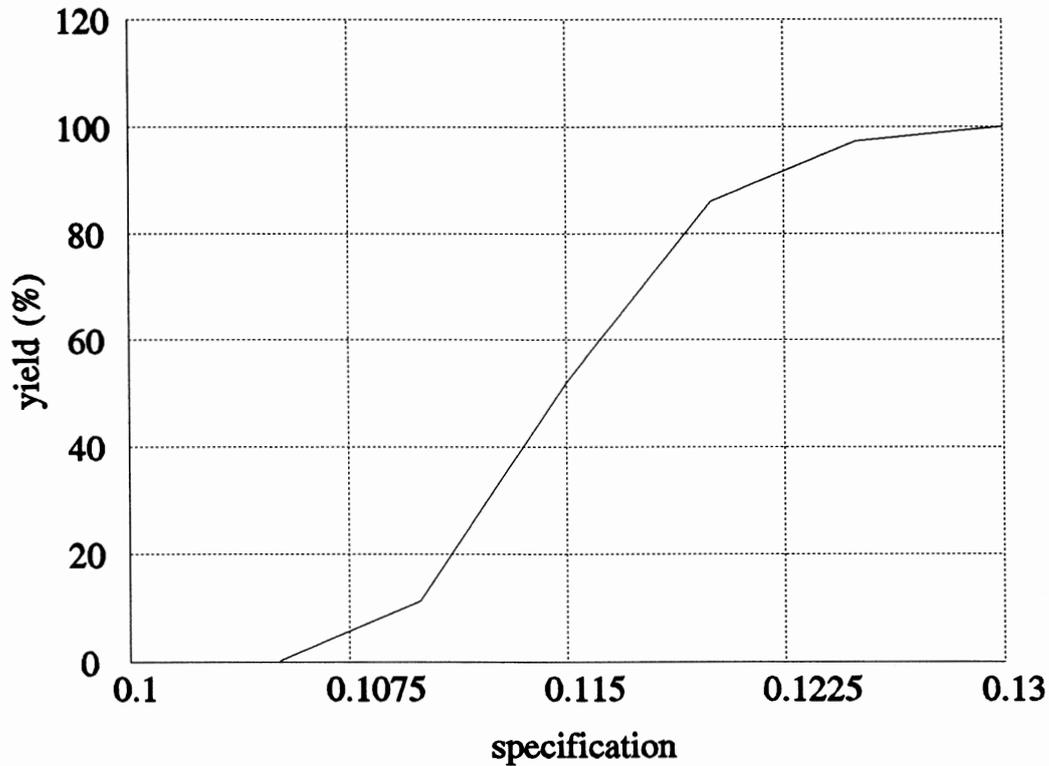
yield is very sensitive to the widths of all the sections and is quite insensitive to the lengths

250 Monte Carlo outcomes used for yield estimation

the results were obtained with little additional computational effort



Yield Sensitivity of the Microstrip Transformer



yield vs. specification on $|S_{11}|$

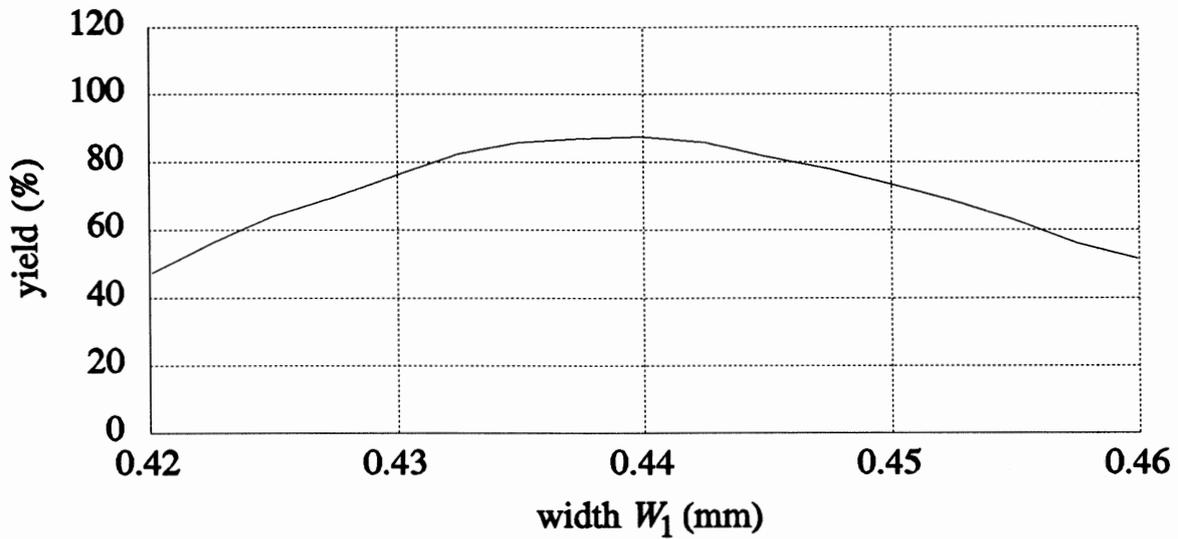
high sensitivity of yield w.r.t. the specification

yield varies from 0% to 100% over a very small range of the specification

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer



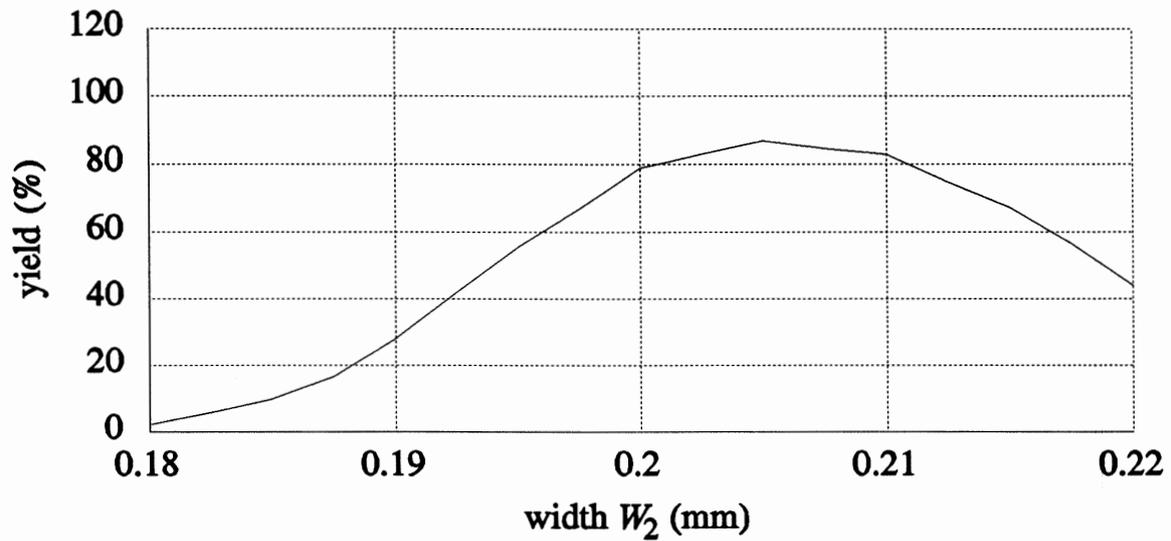
yield vs. W_1

relatively high sensitivity of yield w.r.t. W_1

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer



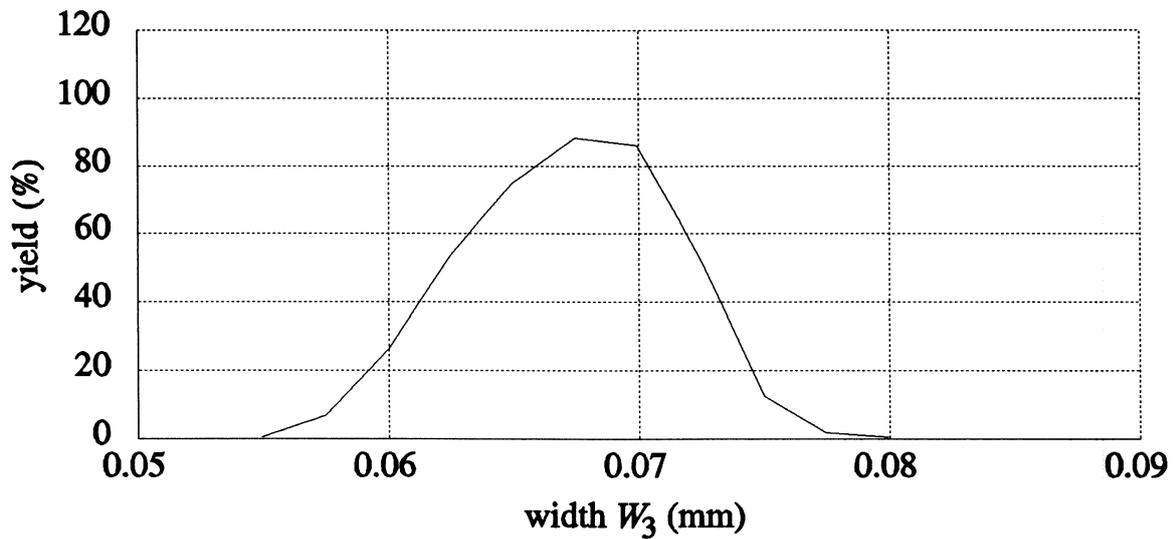
yield vs. W_2

high sensitivity of yield w.r.t. W_2

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer



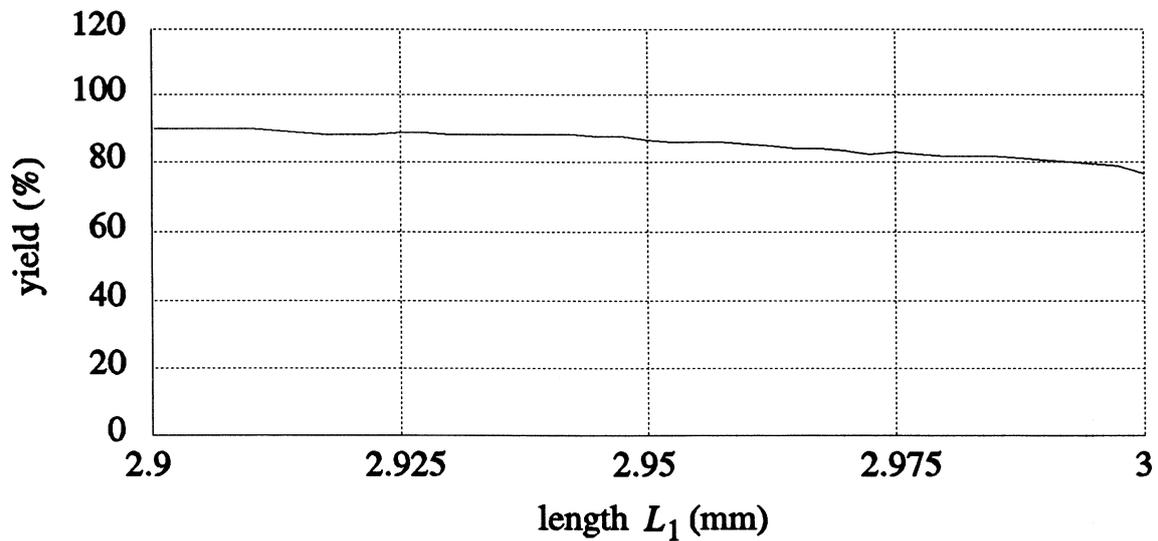
yield vs. W_3

high sensitivity of yield w.r.t. W_3

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer



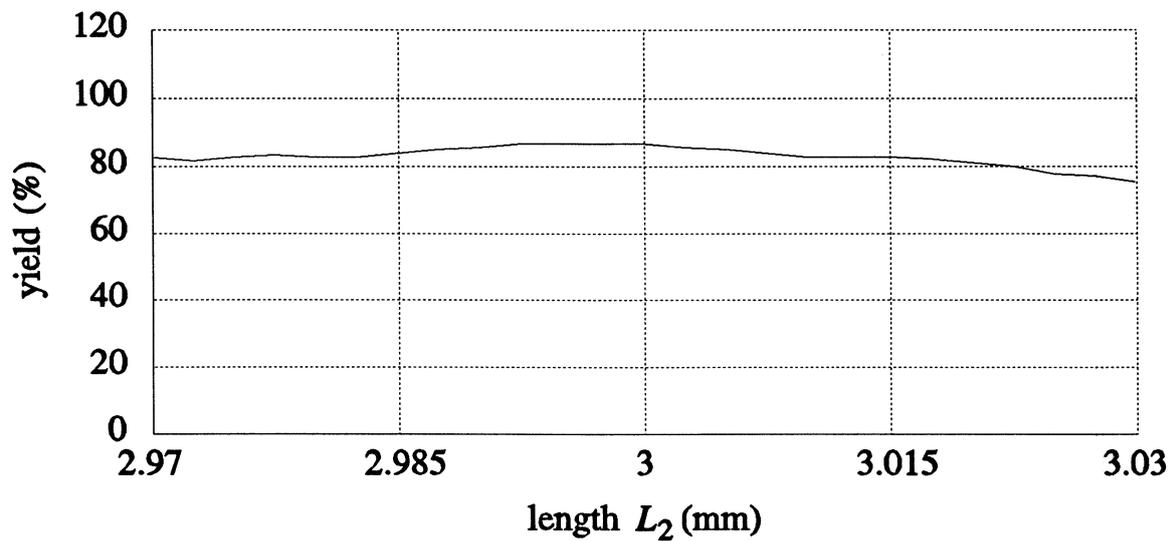
yield vs. L_1

low sensitivity of yield w.r.t. L_1

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer



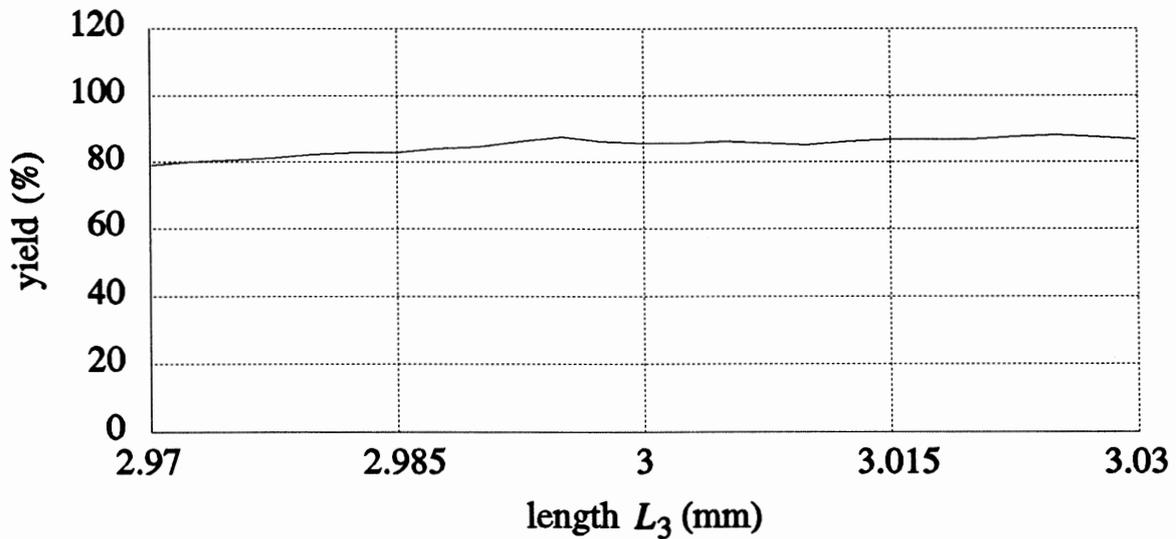
yield vs. L_2

low sensitivity of yield w.r.t. L_2

yield estimated with 250 Monte Carlo outcomes



Yield Sensitivity of the Microstrip Transformer



yield vs. L_3

low sensitivity of yield w.r.t. L_3

yield estimated with 250 Monte Carlo outcomes



Software Implementing Statistical/Diagnosis Concepts

RoMPE™ (1988)

FET parameter extraction (DC data, S parameters)

HarPE™ (1989)

statistical FET parameter extraction (DC, SS, HB)

OSA90™ (1990)

friendly optimization engine for performance- and yield-driven design

OSA90/hope™ (1991)

OSA90 integrated with unified DC/SS/HB

these CAD tools merge multi-circuit/device/domain/bias modeling principles with novel ℓ_1 objectives to enhance precision and uniqueness

robustized modeling and design using Huber functions are coming



Empipe™ (1992)

smart connection of OSA90/hope™ with Sonnet's *em*™ field simulator for interprocessing circuit/field/measurement data

a significant step towards the required integrated approach offering

simulation, modeling, parameter extraction

optimization, sensitivity analysis, statistical analysis

error analysis (probability of satisfying error specs)

automated processing of circuit/field/measurement data

fixed or optimizable geometries simulated by *em*™

recent applications include

EM microstrip filter design

yield-driven direct EM optimization

EM statistical sensitivity analyses

more relevant experimental validation applications to come!



**Parameterized (Optimizable)
Microstrip Library of Empipe™**

bend

cross junction

double patch capacitors

interdigital capacitors

line

mitered bend

open stub

overlay double patch capacitors

rectangular structure

spiral inductors

step junction

symmetrical and asymmetrical folded double stubs

symmetrical and asymmetrical gaps

symmetrical and asymmetrical double stubs

T junction



Conclusions

sensitivity evaluation

well-understood in analysis, design and testing

error analysis

already part of statistical modeling/design systems

measurements made at a difficult frequency

see work on multifrequency testing

too many "confounding" variables

similar treatment as for "soft faults"

the experimenter has a desired outcome in mind

quite an opposite outcome in fault diagnosis!

incorrect objective

answered by diagnosability and testability theory

CAD software

frameworks available for immediate exploitation